NSN 5961-00-781-3087

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Inclosure Material:

Ceramic and metal

End Application:

An/glq-3

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

70.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 0.50 amperes source cutoff current and 1.20 amperes source cutoff current

Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Thread Series Designator:

Unc

Terminal Type And Quantity:

41 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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